MOSFETs Silicon N-channel MOS (U-MOSⅧ-H)

TPH6R003NL

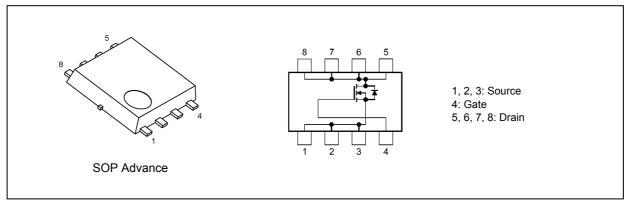
1. Applications

- Switching Voltage Regulators
- DC-DC Converters

2. Features

- (1) High-speed switching
- (2) Small gate charge: $Q_{SW} = 4.3 \text{ nC}$ (typ.)
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 6.8 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 4.5 \text{ V})$
- (4) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- (5) Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_D = 0.2 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25 \,^{\circ}C$ unless otherwise specified)

| Characteris | Symbol | Rating | Unit | | |
|-------------------------------|--------------------------|--------------------|------------------|------------|----|
| Drain-source voltage | | | V _{DSS} | 30 | V |
| Gate-source voltage | | | V _{GSS} | ±20 | 1 |
| Drain current (DC) | (Silicon limit) | (Note 1), (Note 2) | I _D | 57 | A |
| Drain current (DC) | (T _c = 25 °C) | (Note 1) | I _D | 38 | 1 |
| Drain current (pulsed) | (t = 1 ms) | (Note 1) | I _{DP} | 117 | 1 |
| Power dissipation | (T _c = 25 °C) | | PD | 34 | W |
| Power dissipation | (t = 10 s) | (Note 3) | PD | 2.8 | 1 |
| Power dissipation | (t = 10 s) | (Note 4) | PD | 1.6 | 1 |
| Single-pulse avalanche energy | | (Note 5) | E _{AS} | 30 | mJ |
| Avalanche current | · | | I _{AR} | 38 | A |
| Channel temperature | | | T _{ch} | 150 | °C |
| Storage temperature | · | | T _{stg} | -55 to 150 |] |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit | | |
|---------------------------------------|--------------------------|----------|-----------------------|------|------|
| Channel-to-case thermal resistance | (T _c = 25 °C) | | R _{th(ch-c)} | 3.67 | °C/W |
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 3) | R _{th(ch-a)} | 44.6 | |
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 4) | R _{th(ch-a)} | 78.1 | |

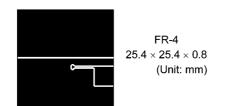
Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Limited by silicon chip capability.

Note 3: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 4: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 5: V_{DD} = 24 V, T_{ch} = 25 °C (initial), L = 16 μ H, I_{AR} = 38 A



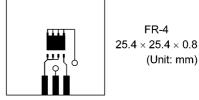


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a) Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

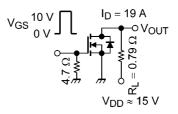
6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------------------|---|-----|------|------|------|
| Gate leakage current | I _{GSS} | V_{GS} = ±20 V, V_{DS} = 0 V | | | ±0.1 | μA |
| Drain cut-off current | I _{DSS} | V _{DS} = 30 V, V _{GS} = 0 V | _ | | 10 | |
| Drain-source breakdown voltage | V _{(BR)DSS} | I _D = 10 mA, V _{GS} = 0 V | 30 | | _ | V |
| | V _{(BR)DSX} | I _D = 10 mA, V _{GS} = -20 V | 15 | _ | _ |] |
| Gate threshold voltage | V _{th} | V _{DS} = 10 V, I _D = 0.2 mA | 1.3 | _ | 2.3 | |
| Drain-source on-resistance | R _{DS(ON)} | V _{GS} = 4.5 V, I _D = 8 A | _ | 6.8 | 8.3 | mΩ |
| | | V _{GS} = 10 V, I _D = 19 A | | 5.2 | 6.0 | |

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|--|-----|------|------|------|
| Input capacitance | C _{iss} | V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz | | 1050 | 1400 | pF |
| Reverse transfer capacitance | C _{rss} | | _ | 37 | 84 | |
| Output capacitance | C _{oss} | | | 600 | _ | |
| Gate resistance | r _g | — | | 1.1 | 1.7 | Ω |
| Switching time (rise time) | tr | See Fig. 6.2.1 | _ | 4.1 | _ | ns |
| Switching time (turn-on time) | t _{on} | | | 11 | _ | 1 |
| Switching time (fall time) | t _f | 1 | | 3.3 | _ | |
| Switching time (turn-off time) | t _{off} |] | | 18 | _ | |



 $\label{eq:buty} \begin{array}{l} \text{Duty} \leq 1 \ \%, \ t_w = 10 \ \mu s \end{array}$ Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (Ta = 25 °C unless otherwise specified)

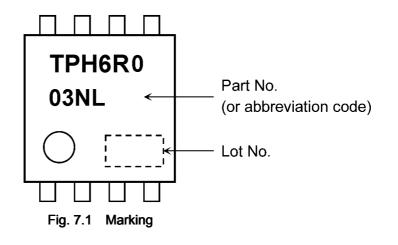
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------------|------------------|---|-----|------|-----|------|
| Total gate charge (gate-source plus | Qg | $V_{DD}\approx 15 \text{ V}, \text{ V}_{GS} \text{ = } 10 \text{ V}, \text{ I}_{D} \text{ = } 38 \text{ A}$ | _ | 17 | _ | nC |
| gate-drain) | | $V_{DD} \approx 15$ V, V_{GS} = 4.5 V, I_D = 38 A | _ | 8.2 | _ | |
| Gate-source charge 1 | Q _{gs1} | $V_{DD} \approx 15 \text{ V}, \text{ V}_{GS}$ = 10 V, I _D = 38 A | | 3.7 | _ | |
| Gate-drain charge | Q _{gd} | | _ | 2.3 | _ | |
| Gate switch charge | Q _{SW} | | _ | 4.3 | | |

6.4. Source-Drain Characteristics ($T_a = 25$ °C unless otherwise specified)

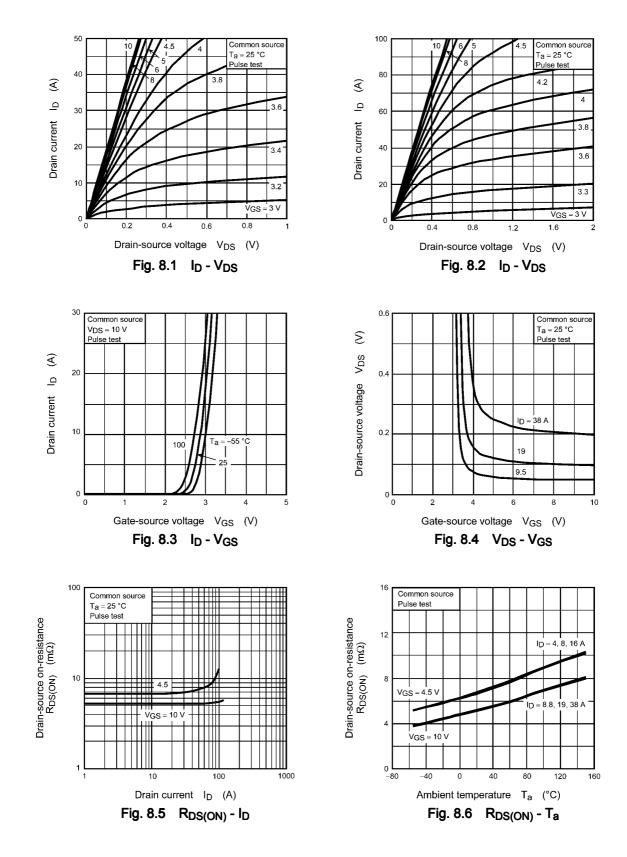
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------------|--------|------------------|---|-----|------|------|------|
| Reverse drain current (pulsed) (No | ote 6) | I _{DRP} | _ | | _ | 117 | А |
| Diode forward voltage | | V _{DSF} | I _{DR} = 38 A, V _{GS} = 0 V | _ | _ | -1.2 | V |

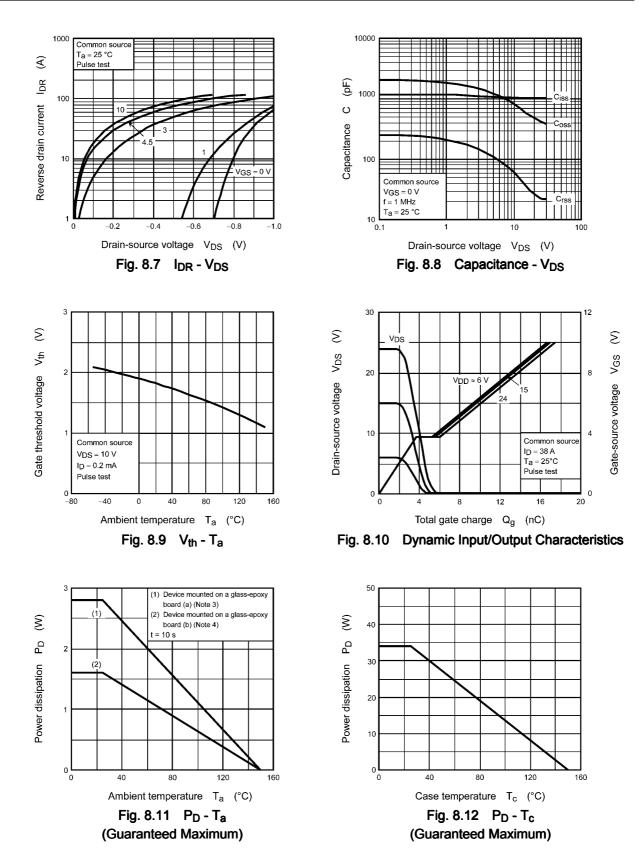
Note 6: Ensure that the channel temperature does not exceed 150 °C.

7. Marking



8. Characteristics Curves (Note)





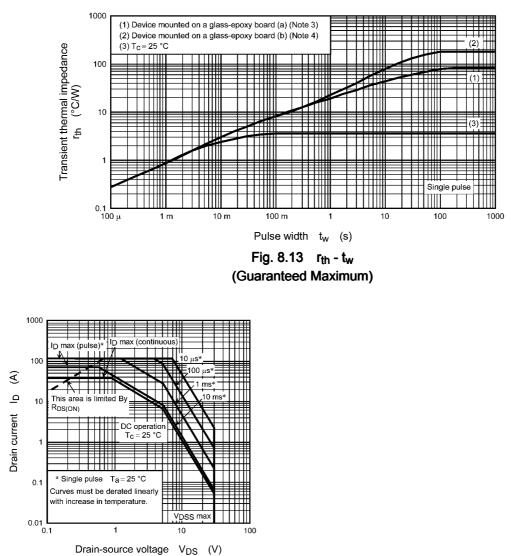


Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

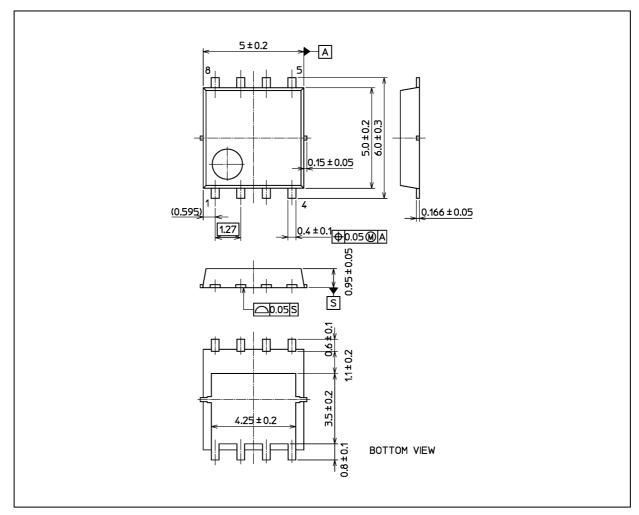
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



TPH6R003NL

Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

TOSHIBA: 2-5Q1S

Nickname: SOP Advance

Package Name(s)

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